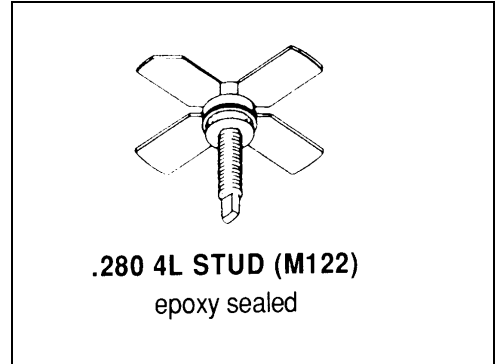


# MS1502

## RF & MICROWAVE TRANSISTORS UHF TV\LINEAR APPLICATIONS

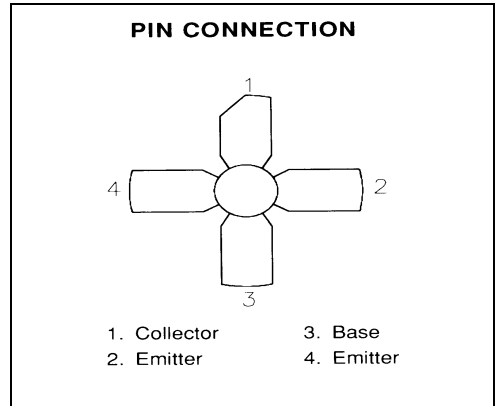
### Features

- 860 MHz
- GOLD METALLIZATION
- CLASS A LINEAR OPERATION
- $P_{OUT} = 0.5$  WATTS
- $G_P = 9.5$  dB MINIMUM
- COMMON EMITTER CONFIGURATION



### DESCRIPTION:

The MS1502 is a silicon NPN bipolar transistor designed for UHF linear applications, specifically TV Bands IV and V. The MS1502 is characterized for high linearity, Class A operation. Device ruggedness and reliability are maximized with emitter ballasting and gold metallization.



### ABSOLUTE MAXIMUM RATINGS ( $T_{case} = 25^{\circ}C$ )

Symbol	Parameter	Value	Unit
$V_{CBO}$	Collector-Base Voltage	45	V
$V_{CEO}$	Collector-Emitter Voltage	25	V
$V_{EBO}$	Emitter-Base Voltage	3.5	V
$I_C$	Device Current	2.0	A
$P_{DISS}$	Power Dissipation	31.8	W
$T_J$	Junction Temperature	+200	$^{\circ}C$
$T_{STG}$	Storage Temperature	-65 to +150	$^{\circ}C$

### Thermal Data

$R_{TH(J-C)}$	Junction-case Thermal Resistance*	5.5	$^{\circ}C/W$
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**ELECTRICAL SPECIFICATIONS (T<sub>case</sub> = 25°C)**
**STATIC**

Symbol	Test Conditions		Value			Unit
			Min.	Typ.	Max.	
<b>BV<sub>CBO</sub></b>	<b>I<sub>C</sub> = 1mA</b>	<b>I<sub>E</sub> = 0mA</b>	<b>45</b>	---	---	<b>V</b>
<b>BV<sub>CEO</sub></b>	<b>I<sub>E</sub> = 20mA</b>	<b>I<sub>B</sub> = 0mA</b>	<b>24</b>	---	---	<b>V</b>
<b>BV<sub>EBO</sub></b>	<b>I<sub>E</sub> = 0.25mA</b>	<b>I<sub>C</sub> = 0mA</b>	<b>3.5</b>	---	---	<b>V</b>
<b>I<sub>CBO</sub></b>	<b>V<sub>CB</sub> = 28 V</b>	<b>I<sub>E</sub> = 0mA</b>	-----	---	<b>0.45</b>	<b>mA</b>
<b>h<sub>FE</sub></b>	<b>V<sub>CE</sub> = 5 V</b>	<b>I<sub>C</sub> = 100mA</b>	<b>15</b>	---	<b>120</b>	---

**DYNAMIC**

Symbol	Test Conditions			Value			Unit
				Min.	Typ.	Max.	
<b>P<sub>OUT</sub></b>	<b>f = 860 MHz</b>	<b>P<sub>IN</sub> = 56mW</b>	<b>V<sub>CE</sub> = 20V</b>	<b>0.5</b>	---	---	<b>W</b>
<b>G<sub>P</sub></b>	<b>f = 860 MHz</b>	<b>P<sub>IN</sub> = 56mW</b>	<b>V<sub>CE</sub> = 20V</b>	<b>9.5</b>	---	---	<b>dB</b>
<b>IMD<sub>3</sub></b>	<b>P<sub>SYNC</sub> = 0.5 W</b>	<b>V<sub>CE</sub> = 20V</b>	<b>I<sub>C</sub> = 220 mA</b>	---	---	<b>-58</b>	<b>dBc</b>
<b>C<sub>OB</sub></b>	<b>f = 1 MHz</b>	<b>V<sub>CB</sub> = 28V</b>		---	---	<b>5</b>	<b>pf</b>

Conditions: **V<sub>CE</sub> = 20V    I<sub>C</sub> = 220 mA**

Conditions: **f<sub>1</sub>=860MHz(-8dBc), f<sub>2</sub>=863.5MHz(-16dBc), f<sub>3</sub>=864.5MHz(-7dBc)**

**PACKAGE MECHANICAL DATA**

